



DONGGUAN NANJING ELECTRONICS LTD.,
MINI MELF Glass-Encapsulate Diodes

LL60 THRU LL60P

Small Signal Fast Switching Diodes

Features

- High reliability
- Low reverse current and low forward voltage

Applications

- Low current rectification and high speed switching

MINI MELF(SOD-80/ LL- 34)



Absolute Maximum Ratings ($T_j = 25^\circ\text{C}$)

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|---------------------------------|-----------------|-------|--------|----------|------|
| Repetitive peak reverse voltage | | LL60 | VRRM | 40 | V |
| | | LL60P | VRRM | 45 | V |
| Peak forward surge current | tp = 1s | LL60 | IFSM | 150 | mA |
| | | LL60P | IFSM | 500 | mA |
| Forward continuous current | Ta=25°C | LL60 | IF | 30 | mA |
| | | LL60P | IF | 50 | mA |
| Storage temperature range | | | Tstg | -65~+125 | |

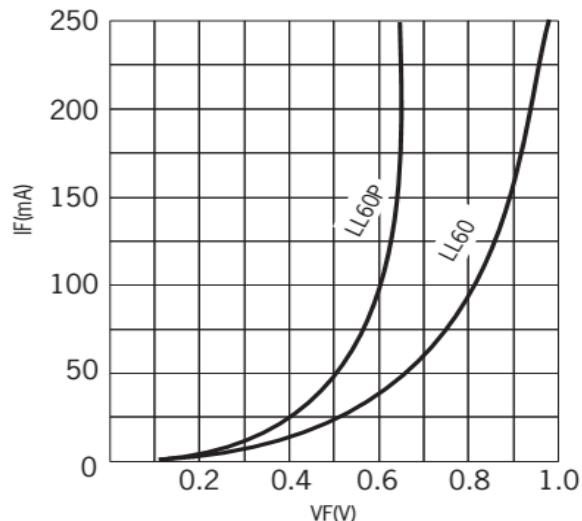
Maximum Thermal Resistance ($T_j = 25^\circ\text{C}$)

| Parameter | Test Conditions | Symbol | Value | Unit |
|------------------|-------------------------------|--------|-------|------|
| Junction ambient | on PC board 50mm• 50mm• 1.6mm | RthJA | 250 | K/W |

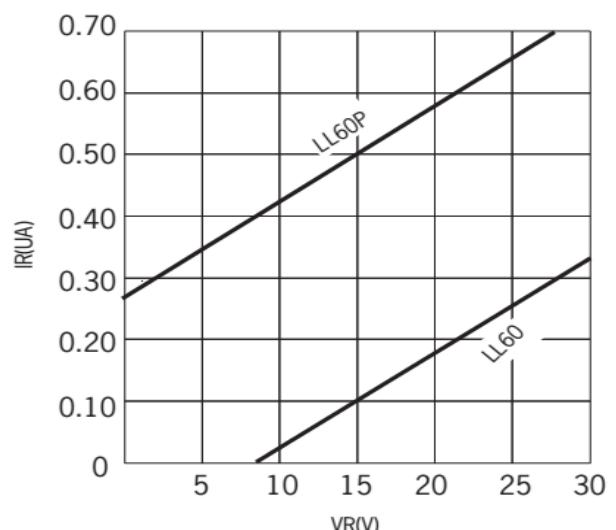
Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------|-------------------------|-------|--------|-----|------|-----|------|
| Forward voltage | IF=1mA | LL60 | VF | | 0.32 | 0.5 | V |
| | | LL60P | VF | | 0.24 | 0.5 | V |
| | IF=30mA | LL60 | VF | | 0.65 | 1.0 | V |
| | IF=200mA | LL60P | VF | | 0.65 | 1.0 | V |
| Reverse current | VR=15V | LL60 | IR | | 0.1 | 0.5 | uA |
| | | LL60P | IR | | 0.5 | 1.0 | uA |
| Junction capacitance | VR=1V, f=1MHz | LL60 | CJ | | 2.0 | | pF |
| | VR=10V, f=1MHz | LL60P | CJ | | 6.0 | | pF |
| Reverse recovery time | IF=IR=1mA In=1mA RC=100 | | v | | | 1.0 | ns |

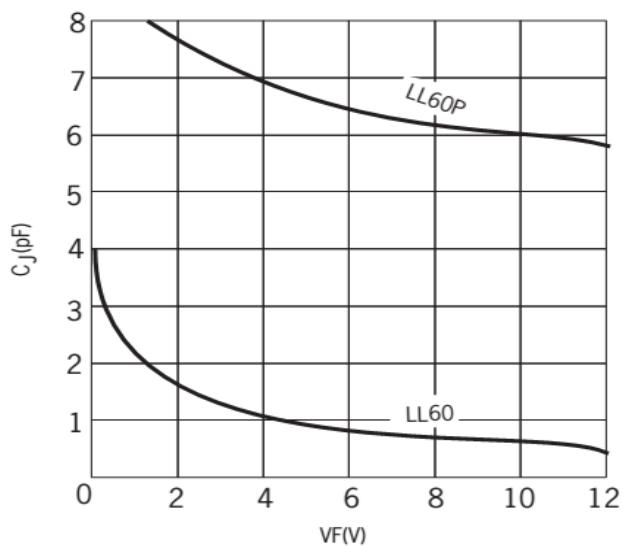
Typical Characteristics



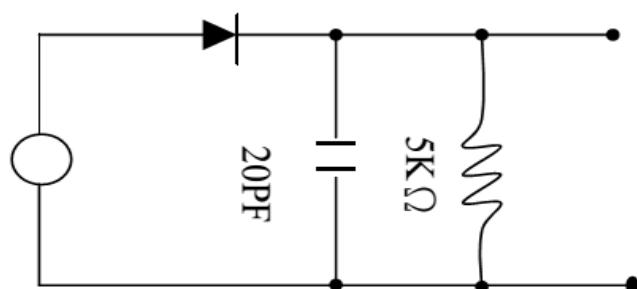
**FIG.1 Foward Current vs.
Forward Voltage**



**FIG.2 Reverse Current vs.
Continuous Reverse Voltage**



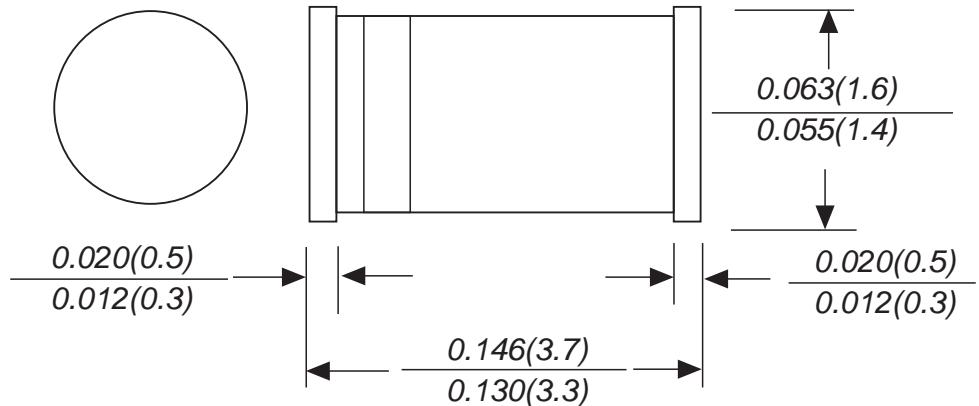
**FIG.3 Junction Capacitance vs.
Continuous Reverse Applied Voltage**



Input 2Vrms

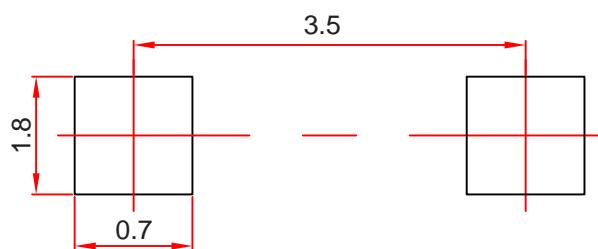
Rectification Efficiency Measurement Circuit

MINI MELF Package Outline Dimensions



Dimensions in millimeters

MINI MELF Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

Packaging Specifications for Surface Mounted Glass Diodes

1. The method of packaging and dimension are shown as below figure. (Dimension in mm)

